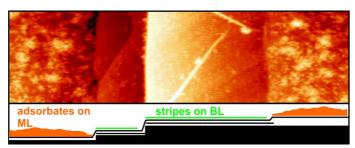
## Observation of 4 nm-Pitch Stripe Domains Formed by Exposing Graphene to Ambient Air

- D. S. Wastl<sup>1</sup>, F. Speck<sup>2</sup>, E. Wutscher<sup>1</sup>, M. Ostler<sup>3</sup>, Th. Seyller<sup>3</sup> and F. J. Giessibl<sup>1</sup>
  - 1: Institut für experimentelle und angewandte Physik, Universität Regensburg, 93053 Regensburg, Germany
  - 2: Lehrstuhl für Technische Physik, Universität Erlangen-Nürnberg, 91058 Erlangen, Germany
    - 3: Institut für Physik, Technische Universität Chemnitz, 09126 Chemnitz,

We study epitaxial graphene on the 6H-SiC(0001) surface under ambient conditions with frequency-modulation atomic force microscopy. We observe large terraces with a self-assembled stripe structure within a highly adsorbate covered surface, on top of thegraphene. To identify the origin of the structure, we compare the experimental data on graphene with calculations that predict the formation of a solid-gas-mono-layer in the solid-liquid interface of hydrophobic surfaces.



**Figure 1:** Epitaxial grown mono- and bilayer graphene on SiC(0001). The monolayer part is covered by a high density of disordered adsorbates, where the bilayer part carries a well ordered stripe structure.

## References

[1] Daniel S. Wastl, Florian Speck, Elisabeth Wutscher, Markus Ostler, Thomas Seyller, and Franz J. Giessibl, under review